TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

2SK3077A

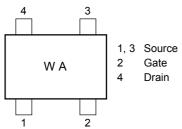
VHF/UHF Band Amplifier Applications

- Output power: $P_0 \ge 20.5 dBmW$
- Gain: $G_p \ge 10.5 dB$
- Drain Efficiency: $\eta D \ge 50\%$

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V _{DSS}	10	V
Gate-source voltage	V _{GSS}	5	V
Drain current	I _D	0.1	А
Power dissipation	PD	0.1	W
Channel temperature	T _{ch}	150	°C
Storage temperature range	T _{stg}	-45~150	°C

Marking

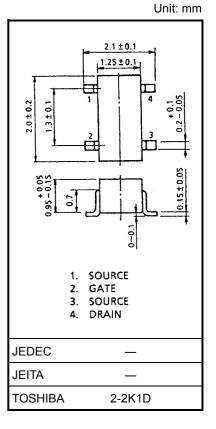


Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output power	PO	V _{DS} = 4.5 V, lidle = 20 mA	20.5			dBmW
Drain efficiency	η _D	$(V_{GS} = adjust)$ f = 470 MHz, P _i = 10dBmW	50	_	_	%
Power gain	GP	$P_i = 470 \text{ MHz}, P_i = 1000 \text{ HW}$	10.5	_	_	dB
Threshold voltage	V _{th}	V _{DS} = 4.8 V, I _D = 0.5 mA	0.25	_	1.25	V
Drain cut-off current	I _{DSS}	V _{DS} = 10 V, V _{GS} = 0 V	_	_	10	μA
Gate-source leakage current	I _{GSS}	V _{GS} = 5 V, V _{DS} = 0 V	_	_	5	μA
Load mismatch (Note 1)		V_{DS} = 6.5 V, f = 470 MHz, P_i = 10dBmW, P_o = 20.5dBmW (V _{GS} = adjust) VSWR LOAD 10:1 all phase	No degradation			

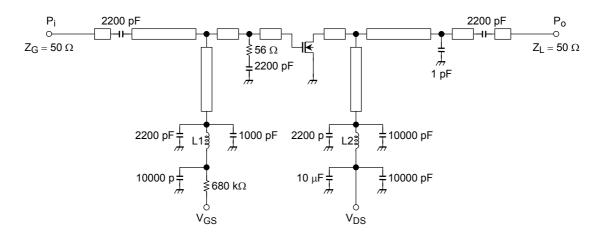
Caution: This transistor is the electrostatic sensitive device. Please handle with caution.

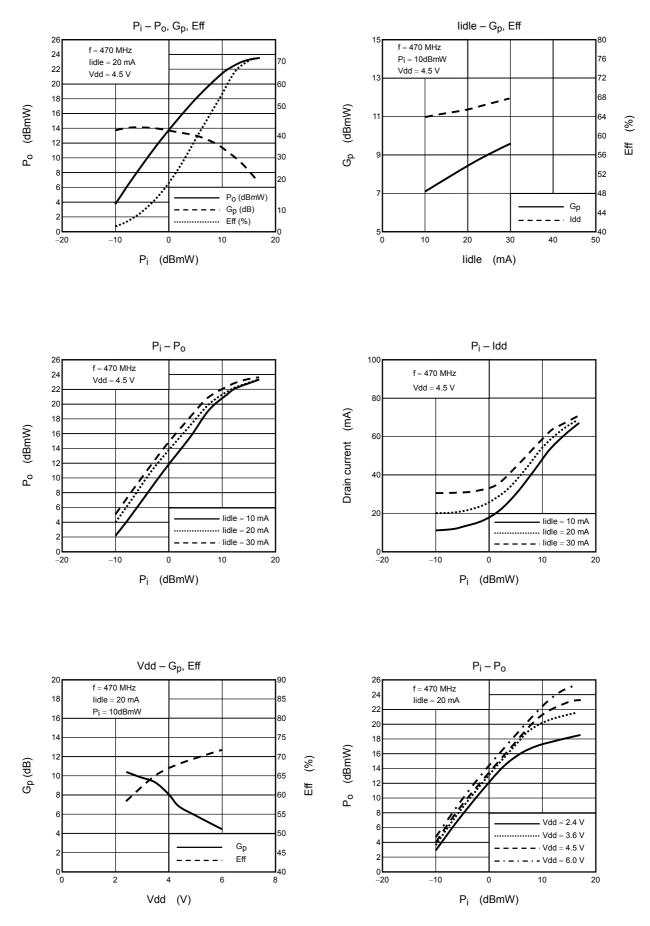
Note 1: When the RF output power test fixture is used



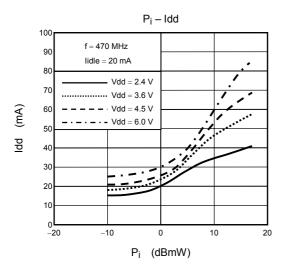
2002-01-09

PF Output Power Test Fixture





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Caution: These are typical curves and devices are not necessarily guaranteed at these curves.



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